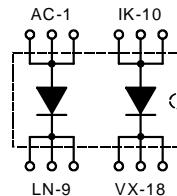


Fast Recovery Epitaxial Diode (FRED)

DSEI 2x121

I_{FAVM} = 2x123 A
V_{RRM} = 200 V
t_{rr} = 35 ns

V _{RSM}	V _{RRM}	Type
V	V	
200	200	DSEI 2x 121-02P



Symbol	Conditions	Maximum Ratings (per diode)		
I _{FRMS}	T _{VJ} = T _{VJM}	150	A	
I _{FAVM} ①	T _C = 70°C; rectangular; d = 0.5	123	A	
I _{FRM}	t _p < 10 µs; rep. rating; pulse width limited by T _{VJM}	600	A	
I _{FSM}	T _{VJ} = 45°C; t = 10 ms (50 Hz), sine	1200	A	
T _{VJ}		-40...+150	°C	
T _{VJM}		150	°C	
T _{stg}		-40...+150	°C	
P _{tot}	T _C = 25°C	250	W	
V _{ISOL}	50/60 Hz, RMS	2500	V~	
	I _{ISOL} ≤ 1 mA	3000	V~	
M _d	Mounting torque (M4)	1.5 - 2.0 14 - 18	Nm lb.in.	
Weight		20	g	

Symbol	Conditions	Characteristic Values (per diode)		
		typ.	max.	
I _R	T _{VJ} = 25°C V _R = V _{RRM} T _{VJ} = 25°C V _R = 0.8 • V _{RRM} T _{VJ} = 125°C V _R = 0.8 • V _{RRM}	1 0.5 20	mA	mA
V _F	I _F = 120 A; T _{VJ} = 150°C T _{VJ} = 25°C	0.89	0.95 1.10	V V
V _{T0} r _T	For power-loss calculations only T _{VJ} = T _{VJM}		0.7 2.1	V mΩ
R _{thJC} R _{thCK}		0.1	0.7 K/W	K/W K/W
t _{rr}	I _F = 1 A; -di/dt = 400 A/µs V _R = 30 V; T _{VJ} = 25°C	35	50	ns
I _{RM}	V _R = 100 V; I _F = 100 A; -di _F /dt = 200 A/µs L ≤ 0.05 µH; T _{VJ} = 100°C	12	15	A
d _s d _A a	Creeping distance on surface Creeping distance in air Allowable acceleration	min. 11.2 min. 11.2 max. 50	mm mm m/s ²	mm mm m/s ²

① I_{FAVM} rating includes reverse blocking losses at T_{VJM}, V_R = 0.8 V_{RRM}, duty cycle d = 0.5
Data according to IEC 60747

Features

- 2 independent FRED in 1 package
- Isolation voltage 3000 V~
- Planar passivated chips
- Leads suitable for PC board soldering
- Very short recovery time
- Soft recovery behaviour

Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Low noise switching
- Small and light weight

Recommended replacement:
DSEI 2x161-02P/DSEI 2x121-02A

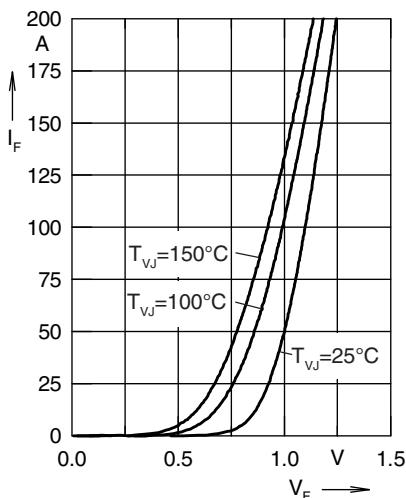
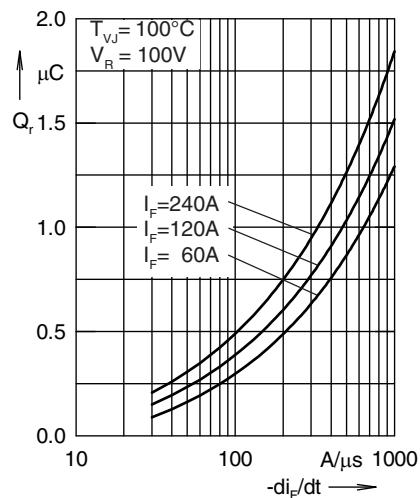
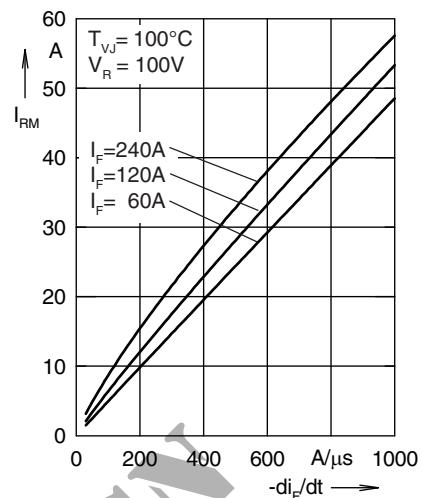
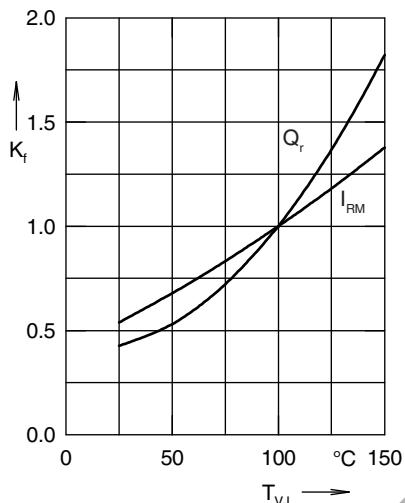
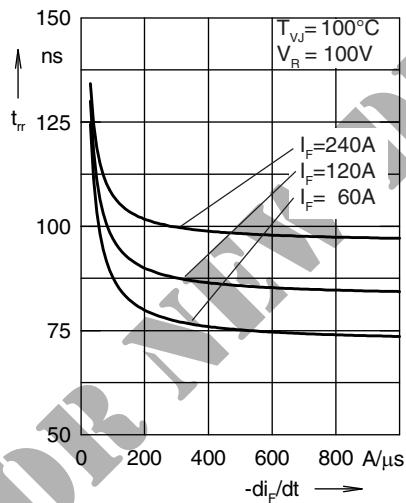
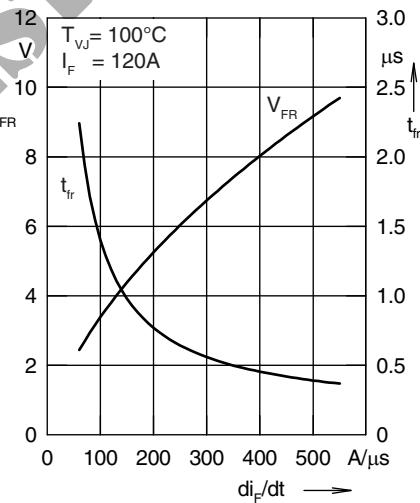
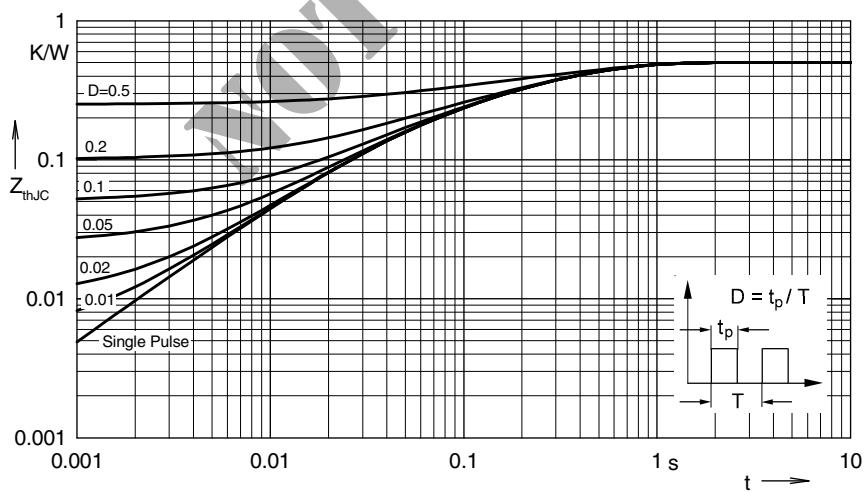
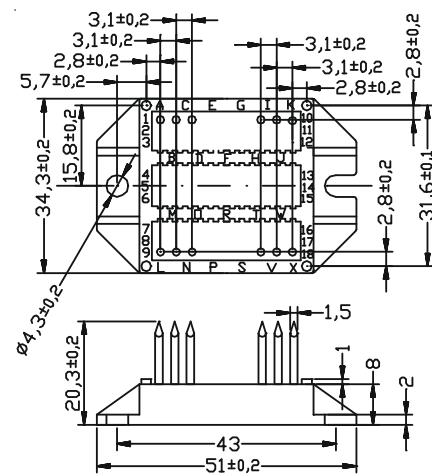
Fig. 1 Forward current I_F versus V_F Fig. 2 Typ. reverse recovery charge Q_r versus $-di_F/dt$ Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$ Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ} Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$ Fig. 6 Typ. peak forward voltage V_{FR} and t_{rr} versus di_F/dt 

Fig. 7 Transient thermal impedance junction to case at various duty cycles

Dimensions in mm (1mm = 0.0394")



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